Monolithic Linear IC



Suited for use in speed control of general-purpose compact DC motors for radio-cassette recorders, car stereos

Features and Functions

- Wide operating voltage range (4.5 to 18V)
- Possible to make the equipment compact because of minimum number of external parts required and small-sized package
- · Facilitates speed control
- · Easy to control rotational speed from low speed to high speed
- · On-chip kickback absorber
- High stability in oscillation
- · Facilitates heat radiation because of the use of a fin

Maximum Ratings at Ta = 25° Maximum Supply Voltage Allowable Power Dissipation	V _S max Pd max	20 Heat is radiated to Cu foil of 1cm ² : 1.7W 1.0				unit V W
Operating Temperature	Topr				to + 80	°C
Storage Temperature	Tstg	~		-40 tc	o + 150	°C
Starting Current	I _M max	Switch ON or lock			1.4	Α
Operating Conditions at Ta = 25°C						
Supply Voltage	V_S				3 to 18	V
Control Resistance	RA + RB			,	100	kΩ
Operating Characteristics at Reference Voltage 2nd Reference Voltage Quiescent Flow-in Current Shunt Ratio Residual Voltage	Vref Vref' Id K V _(sat)	$V_{S} = 8V, I_{M} = 100mA$ $V_{S} = 8V, I_{M} = 100mA$ $V_{S} = 8V, I_{M} = 0$ $V_{S} = 8V, I_{M} = 0 - 100mA$ $V_{S} = 3V, I_{M} = 200mA$	min 1.1 2.0 0.5 22	typ 1.2 2.15 1.73 24 1.1	max 1.3 2.3 2.5 26 1.4	unit V MA V
Voltage Characteristic	$\frac{\Delta Vref}{Vref} / \Delta V_S$	$V_{S} = 3 \text{ to } 18V, I_{M} = 100 \text{ mA}$	-0.02	0	+0.02	%/V
of Reference Voltage	Vret	Continued on next				page.
		Packago Dimons	oncions 1			2



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			min	typ	max	unit
Voltage Characteristic of 2nd Reference Voltage	$\frac{\Delta Vref'}{Vref'}/\Delta V_S$	$V_{S} = 3 \text{ to } 18V, I_{M} = 100 \text{ mA}$	0.05	0.025	0.1	%/V
[Voltage Characteristic of Quiescent Flow-in Current	$\frac{\Delta Id}{Id} / \Delta V_{S}$	$V_S = 3$ to $18\dot{V}$, $I_M = 0$		0.3	0.8	%/V.
Voltage Characteristic of Shunt Ratio	$\frac{\Delta K}{K} / \Delta V_{S}$	$V_S = 3$ to 18V, $I_M = 0-100$ mA	-0.8	-0.3	0.3	%/V
Current Characteristic of Reference Voltage	$\frac{\Delta Vref}{Vref} / \Delta I_M$	$V_{S} = 8V, I_{M} = 50 \text{ to } 150 \text{ mA}$	-0.002	0	0.0029	%/mA
Current Characteristic of 2nd Reference Voltage	$\frac{\Delta Vref'}{Vref'}/\Delta I_M$	$V_{S} = 8V, I_{M} = 50$ to 150mA	- 0.1 -	- 0.013	0.059	%/mA
Current Characteristic of Shunt Ratio	$\frac{\Delta K}{K} / \Delta I_M$	$V_{S} = 8V, I_{M} = 50 - 100mA$ to $150 - 200mA$		0.008	0.025 %	%/mA
Temperature Characteristic of Reference Voltage	<u>ΔVref</u> /ΔTa	$V_{S} = 8V, I_{M} = 100 \text{mA},$ Ta = 20 to 80°C		0		%/°C
Temperature Characteristic of 2nd Reference Voltage	$\frac{\Delta Vref'}{Vref'}/\Delta Ta$	$V_S = 8V, I_M = 100 \text{ mA},$ Ta = 20 to 80°C		0		%/°C
[Temperature Characteristic of Quiescent Flow-in Current	$\frac{\Delta Id}{Id} / \Delta Ta$	$V_S = 8V, I_M = 100 \text{mA},$ Ta = 20 to 80°C		0.12		%/°C
Temperature Characteristic of Shunt Ratio	$\frac{\Delta K}{K} / \Delta T_a$	$V_S = 8V, I_M = 100mA,$ Ta = 20 to 80°C		0.02		%/°C

Test Circuit



1) Reference voltage (Vref)

Measure the voltage across pins $V_{\rm S}$ and $V_{\rm R}$ with the SW ON.

- 2) 2nd reference voltage (Vref')
- Measure the voltage across pins $V_{\mbox{\scriptsize S}}$ and OUT with the SW ON. 3) Quiescent flow-in current (Id)

Measure using the voltage across the resistor of 10Ω with the SW OFF.

4) Shunt ratio (K)

With the SW OFF, measure Id,Id1 at $I_M = I_M 1$ and Id,Id2 at $I_M = I_M 2$ and calculate using the following formula.

$$K = \frac{(I_M 2 - I_M I)}{(Id2 - Id1)}$$

5) Residual voltage (V_{sat}) With the SW OFF, measure the voltage across pins OUT and GND at $V_S=3V$, $I_M=200mA$.



Block Diagram

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